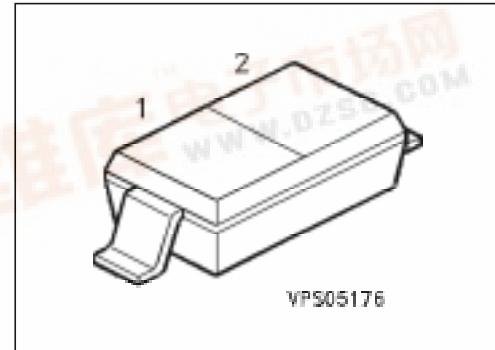


SIEMENS**Silicon Variable Capacitance Diode****BB 811**

- Frequency range up to 2 GHz;
special design for use in TV-sat indoor units



| Type | Marking | Ordering Code (tape and reel) | Pin Configuration | Package ¹⁾ |
|--------|---------|----------------------------------|-----------------------|-----------------------|
| BB 811 | white T | Q62702-B478 | 1 ─ ┌── 2 EHA07001 | SOD-123 |

Maximum Ratings

| Parameter | Symbol | Values | Unit |
|--|-----------|----------------|------------------|
| Reverse voltage | V_R | 30 | V |
| Forward current, $T_A \leq 60^\circ\text{C}$ | I_F | 20 | mA |
| Operating temperature range | T_{op} | - 55 ... + 125 | $^\circ\text{C}$ |
| Storage temperature range | T_{stg} | - 55 ... + 150 | |

Thermal Resistance

| | | | |
|--------------------|-------------|------------|-----|
| Junction - ambient | $R_{th JA}$ | ≤ 450 | K/W |
|--------------------|-------------|------------|-----|

Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

| Parameter | Symbol | Values | | | Unit |
|---|--------------------------|-------------|-------------|------------|----------|
| | | min. | typ. | max. | |
| Reverse current $V_R = 30\text{ V}$ $V_R = 30\text{ V}, T_A = 85^\circ\text{C}$ | I_R | — — | — — | 20 500 | nA |
| Diode capacitance, $f = 1\text{ MHz}$ $V_R = 1\text{ V}$ $V_R = 28\text{ V}$ | C_T | 7.8 0.85 | 8.8 1.02 | 9.8 1.2 | pF |
| Capacitance ratio $f = 1\text{ MHz}, V_R = 1\text{ V}/28\text{ V}$ | $\frac{C_{T1}}{C_{T28}}$ | 7.8 | 8.6 | 9.5 | — |
| Series resistance $f = 100\text{ MHz}, C_T = 9\text{ pF}$ | r_s | — | 1 | — | Ω |
| Case capacitance $f = 1\text{ MHz}$ | C_c | — | 0.1 | — | pF |
| Capacitance matching $f = 1\text{ MHz}, V_R = 0.5 \dots 28\text{ V}$ | $\frac{\Delta C_T}{G}$ | — | — | 3 | % |
| Series inductance | L_s | — | 2.8 | — | nH |

Diode capacitance $C_T = f(V_R)$ $f = 1\text{ MHz}$ 